

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7	("4734340").PN. OR ("5923524").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/09/29 15:42
L2	5663	438/240.ccls. 438/253.ccls. 438/396.ccls. 438/685.ccls. 438/686.ccls. 438/785.ccls.	US-PGPUB; USPAT	OR	OFF	2005/09/29 15:44
L3	50	L2 and (((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") same ((titanium adj (oxide dioxide)) "tio.sub.2") same (ald ale (atomic adj layer)))	US-PGPUB; USPAT	OR	ON	2005/09/29 15:44
L4	7	((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") and ((titanium adj (oxide dioxide)) "tio.sub.2") and (ald ale (atomic adj layer))	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/29 15:48
L5	78	((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") and ((titanium adj (oxide dioxide)) "tio.sub.2") and (capacitor memory dram)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/29 15:49
L6	116	(((((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") same ((titanium adj (oxide dioxide)) "tio.sub.2")) same (ald ale (atomic adj layer))) and (capacitor memory dram ((lower bottom first) adj electrode)))	US-PGPUB; USPAT	OR	ON	2005/09/29 17:08
L7	5663	438/240.ccls. 438/253.ccls. 438/396.ccls. 438/685.ccls. 438/686.ccls. 438/785.ccls.	US-PGPUB; USPAT	OR	OFF	2005/09/29 16:18
L8	239	L7 and ((capacitor memory dram ((lower bottom first) adj electrode)) same ((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") same ((titanium adj (oxide dioxide)) "tio.sub.2"))	US-PGPUB; USPAT	OR	ON	2005/09/29 16:08
L9	1372	438/240.ccls.	US-PGPUB; USPAT	OR	OFF	2005/09/29 16:18
L10	265	(((((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") and ((titanium adj (oxide dioxide)) "tio.sub.2") and (capacitor memory dram ((lower bottom first) adj electrode))))).clm.	US-PGPUB	OR	ON	2005/09/29 17:11

L11	259	((((tantalum adj (oxide pentoxide)) "ta.sub.2o.sub.5" "ta.sub.2 o.sub.5") and ((titanium adj (oxide dioxide)) "tio.sub.2") and (capacitor memory dram ((lower bottom first) adj electrode)) and (semiconductor silicon dielectric insulat\$6 integrated ic)).clm.	US-PGPUB	OR	ON	2005/09/29 17:11
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